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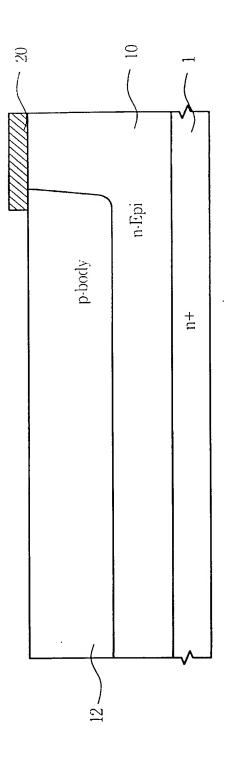
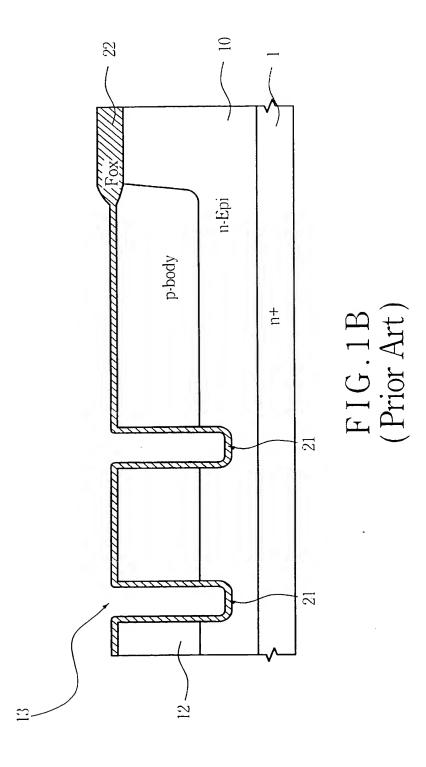
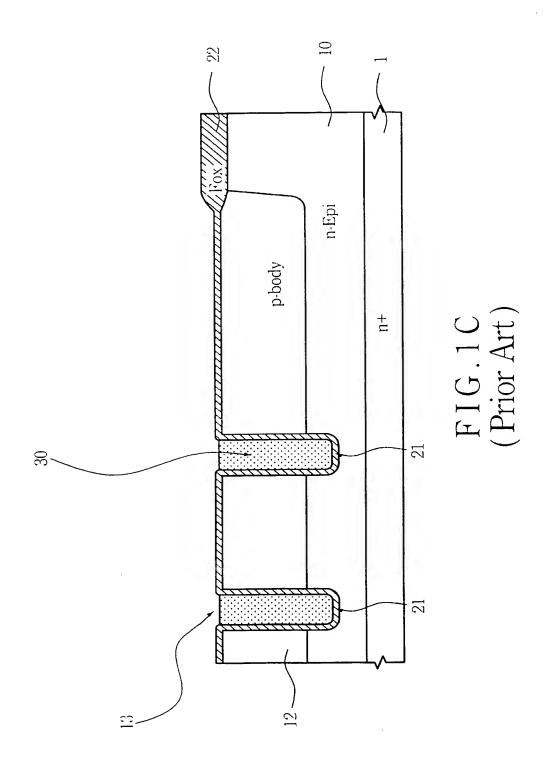


FIG. LA (Prior Art)

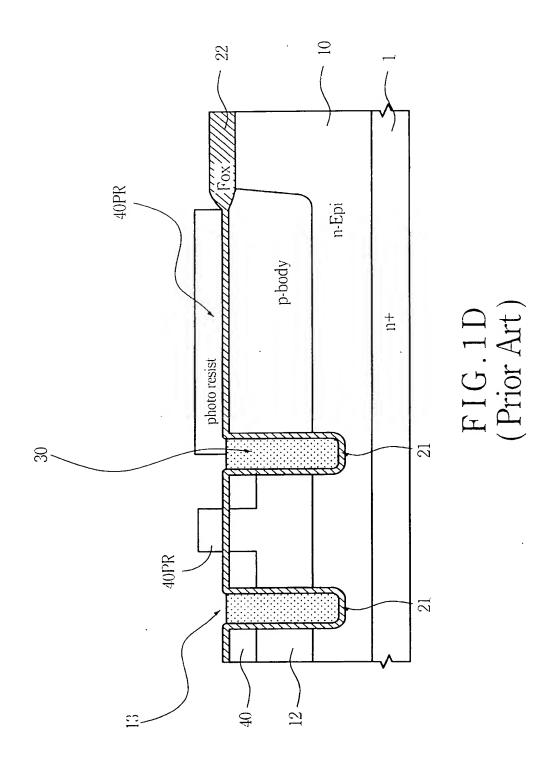
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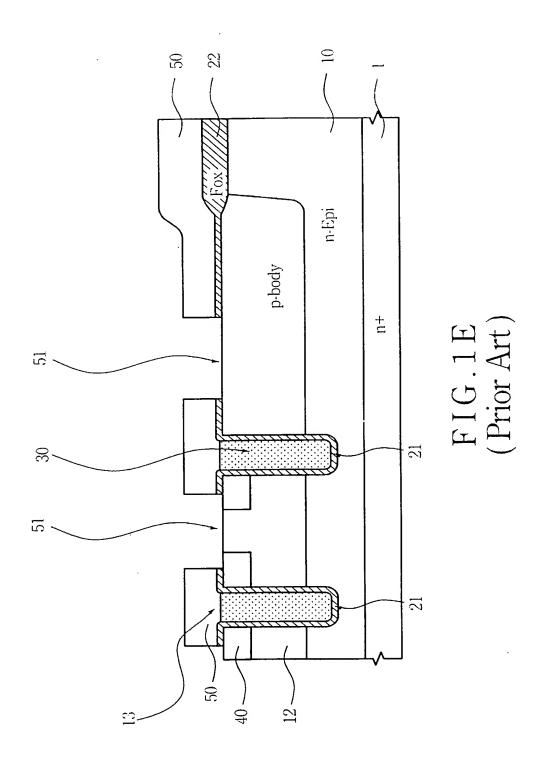
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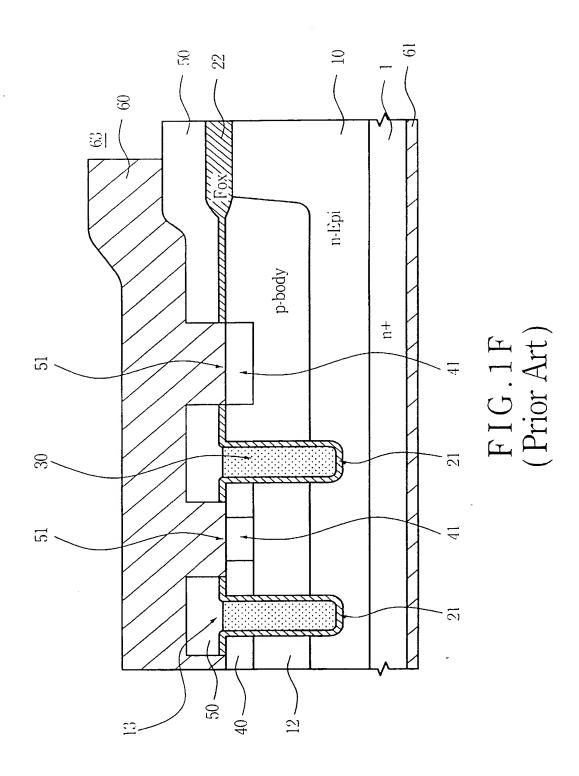
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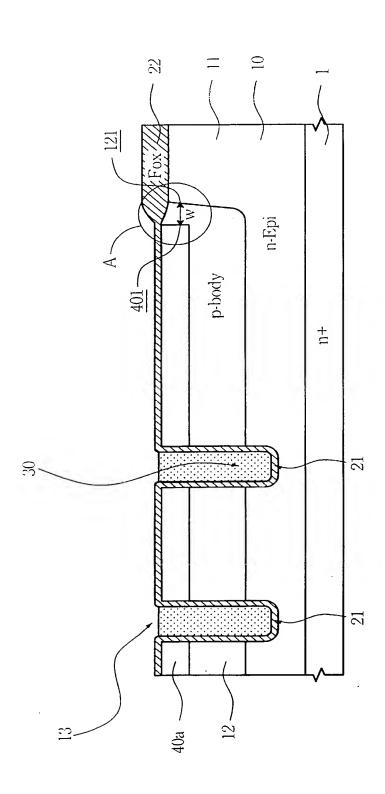
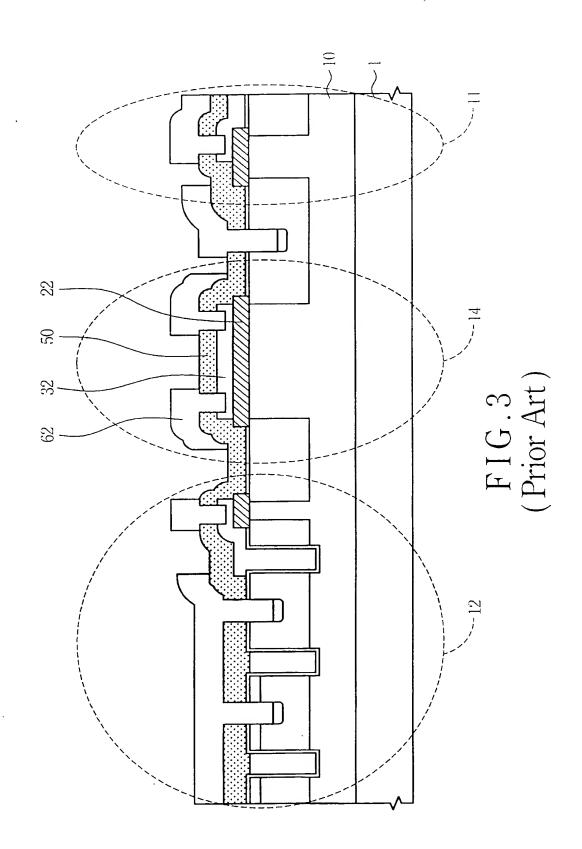
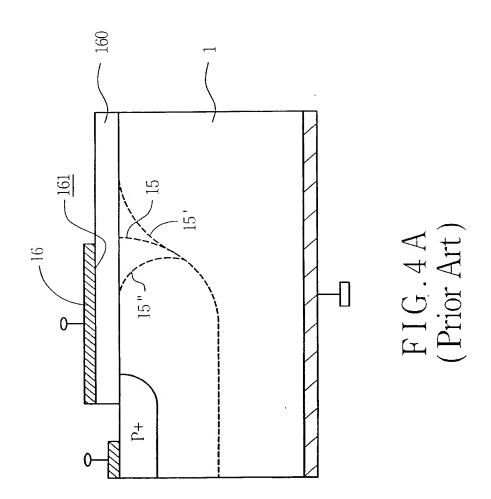


FIG.2 (Prior Art)

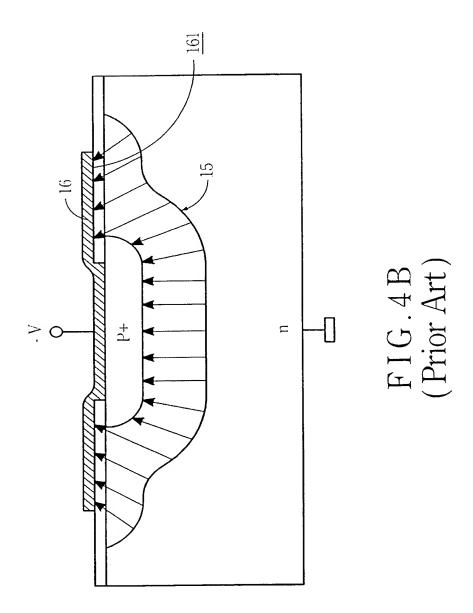
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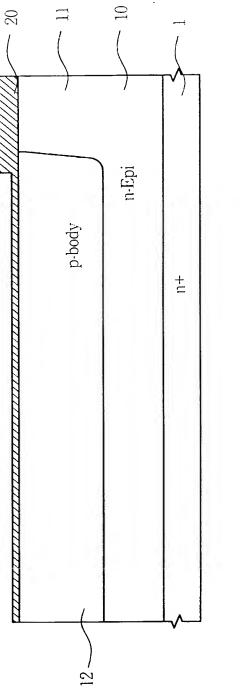
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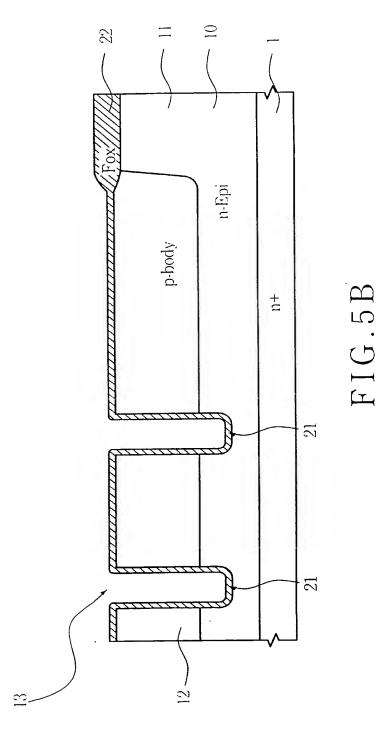


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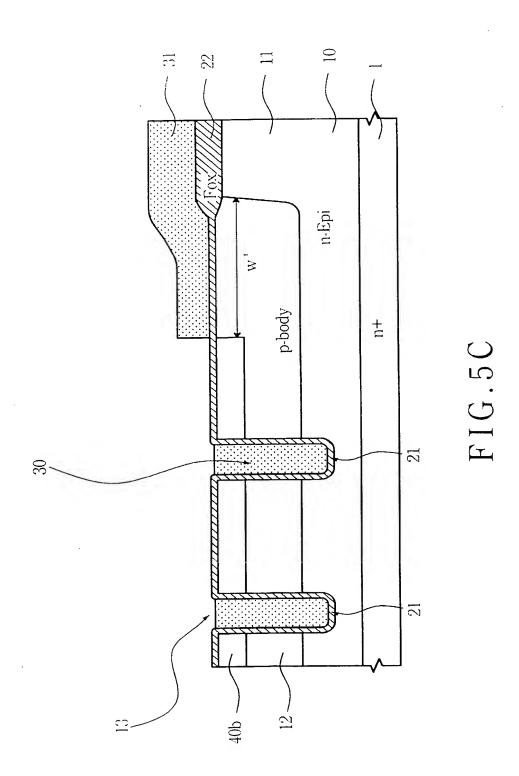


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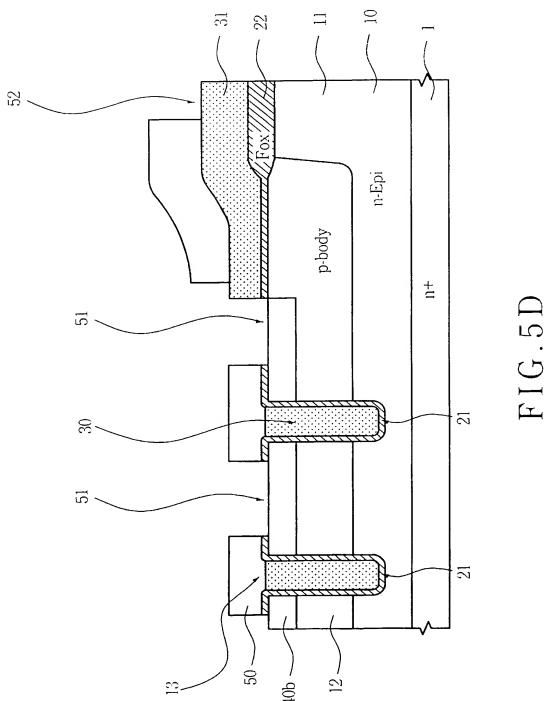
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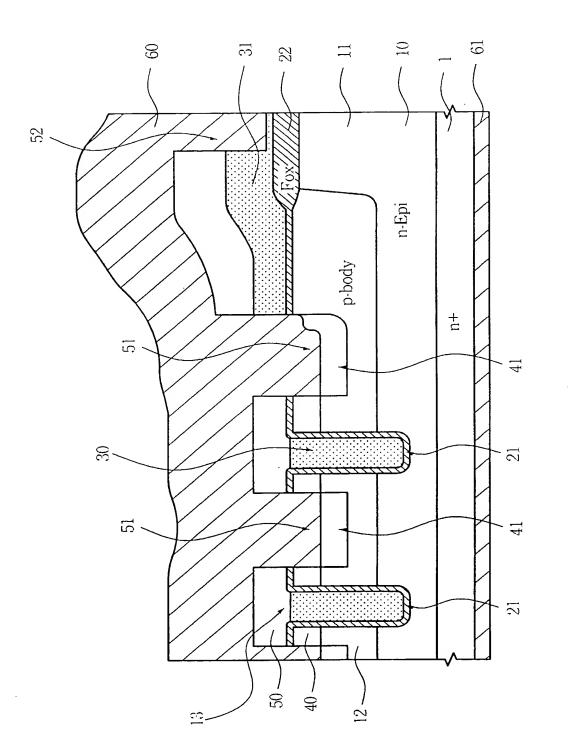
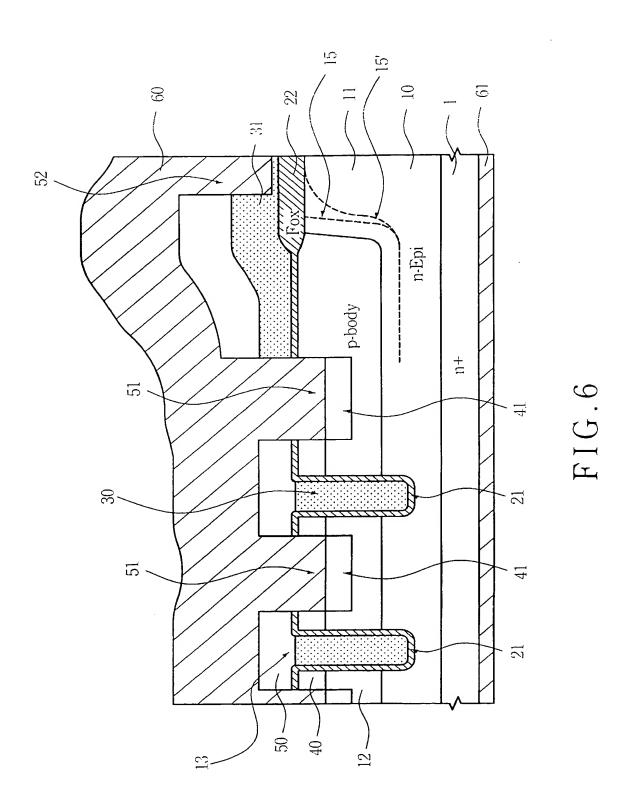


FIG.5E

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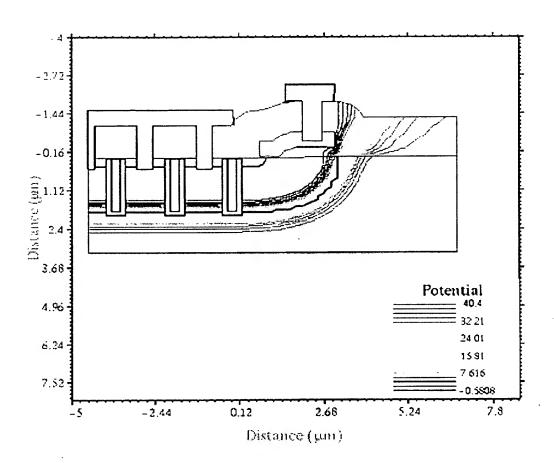


FIG. 7

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